United States Patent [19]

Ernsthausen

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[54] **METHOD OF MAKING GASEOUS DISCHARGE DEVICE HAVING LOWER OPERATING VOLTAGES OF INCREASED UNIFORMITY**

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[22] Filed: **Aug. 6, 1973**

[21] Appl. No.: **385,974**

Related U.S. Application Data

[63] Continuation of Ser. No. 70,523, Sept. 8, 1970, abandoned.

[52] **U.S. Cl.** **29/25.11;** 117/215; 313/188; 316/20

[51] **Int. Cl.²** **H01J 9/00**

[58] **Field of Search**..... 29/25.11, 25.14, 25.17; 316/1, 3, 4, 5, 6, 20; 313/109.5, 210, 220, 221, 201, 188; 315/169 R; 117/69, 215

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[57] **ABSTRACT**

There is disclosed a multiple gaseous discharge display/memory panel having an electrical memory and capable of producing a visual display, the panel being characterized by an ionizable gaseous medium in a gas chamber formed by a pair of opposed dielectric material charge storage members which are respectively backed by a series of parallel-like conductor (electrode) members, the conductor members behind each dielectric material member being transversely oriented with respect to the conductor members behind the opposing dielectric material member so as to define a plurality of discrete discharge volumes constituting a discharge unit, the surface of the dielectric material having a first layer of at least one oxide of Al, Ti, Zr, Hf, and Si and a second layer of lead oxide, both layers being applied to the surface in an amount sufficient to provide substantially lower and more stable panel operating voltages which do not significantly change with panel operating time.

2 Claims, 5 Drawing Figures

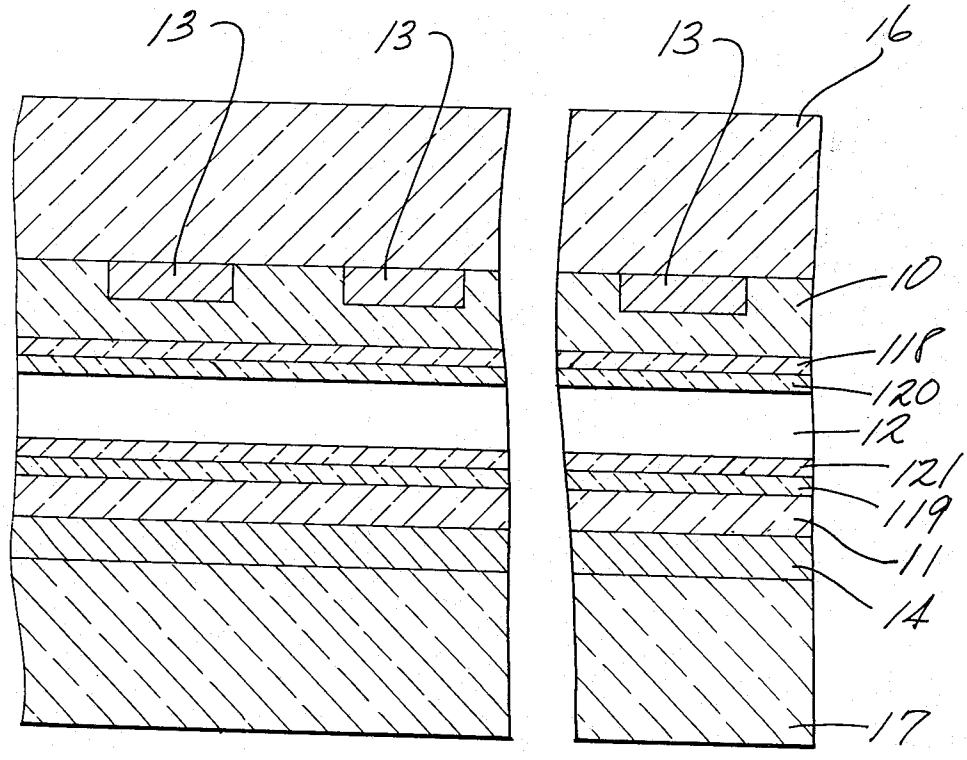


FIG. 2

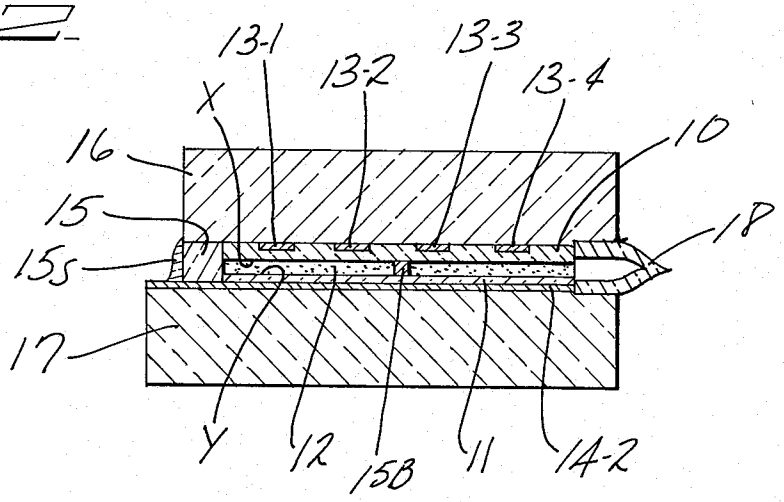

13-1
13-2
13-3
13-4
X
16
10
15
18
15S
17
Y
12
15B
11
14-2

FIG. 1

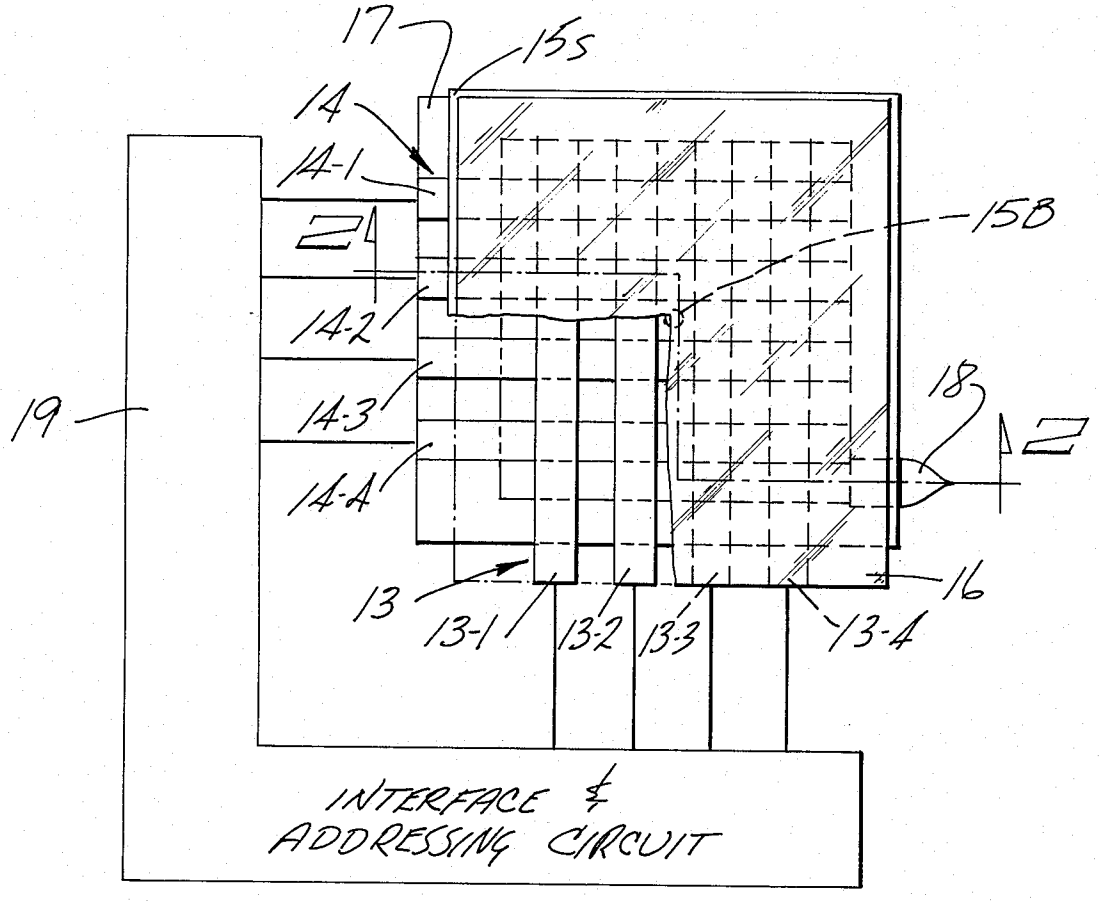

17
15S
14
14-1
15B
14-2
14-3
19
18
Z
14-4
13
16
13-1
13-2
13-3
13-4
INTERFACE &
ADDRESSING CIRCUIT

FIG. 3

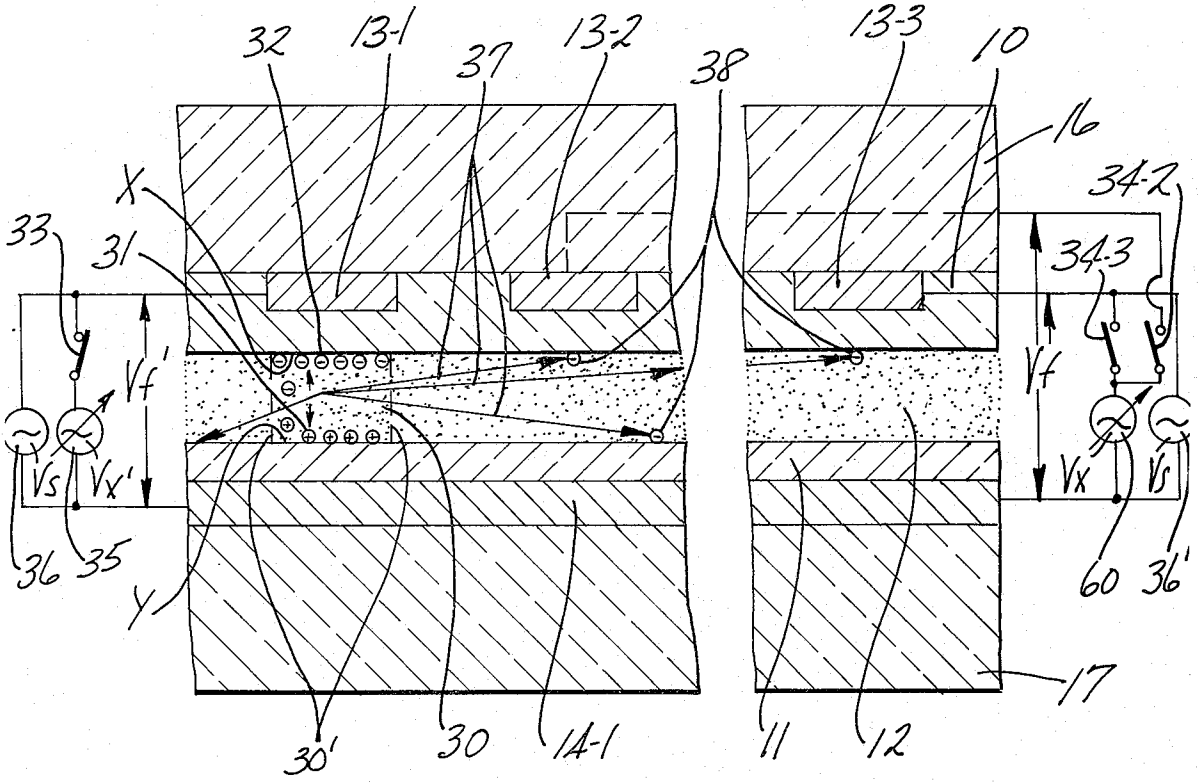

32
13-1
37
13-2
38
13-3
10
16
34-2
34-3
X
33
31
Vf'
Vs
Vx'
36
35
Y
Vf
Vx
Vs
60
36'
30'
30
14-1
11
12
17

FIG. 4

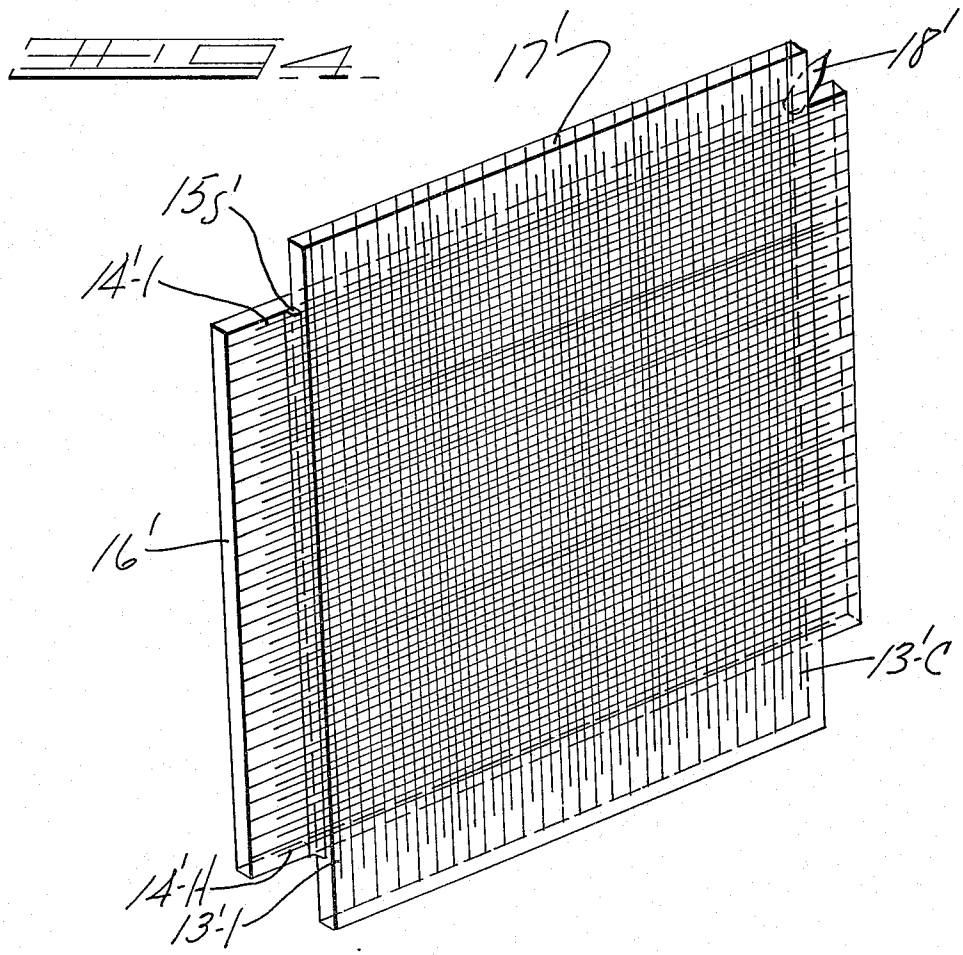
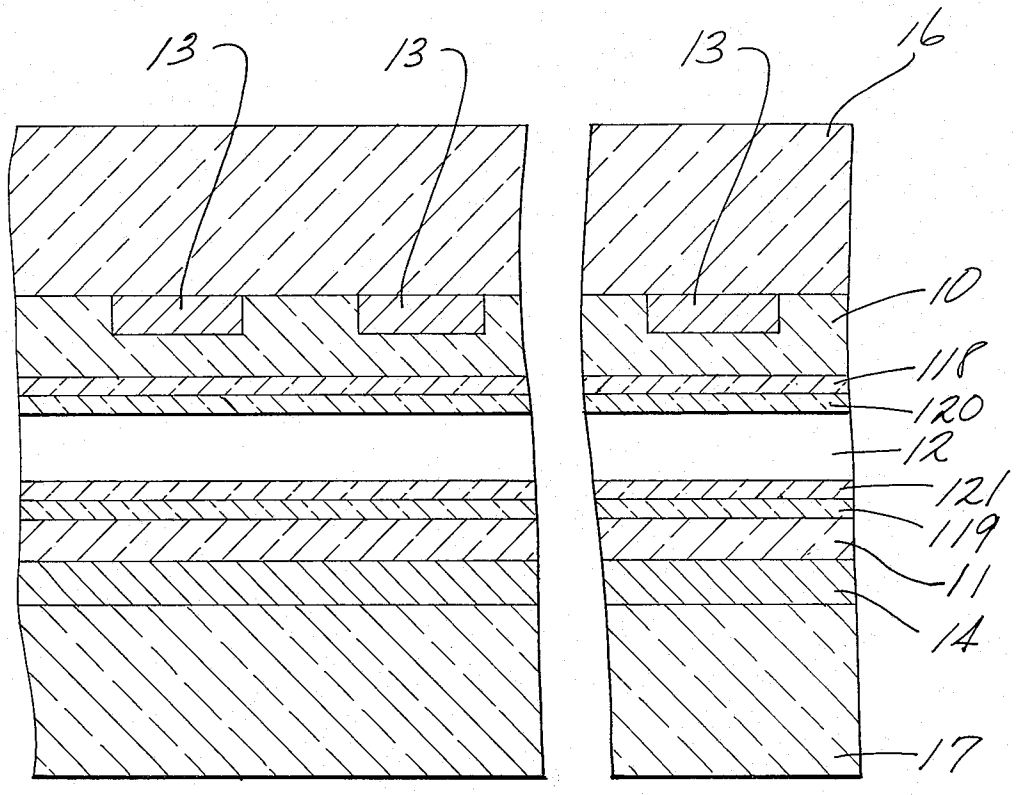

17'
18'
15s'
14'-1
16'
13'-C
14'-H
13'-1

FIG. 5



METHOD OF MAKING GASEOUS DISCHARGE DEVICE HAVING LOWER OPERATING VOLTAGES OF INCREASED UNIFORMITY

RELATED APPLICATION

This is a continuation of U.S. patent application Ser. No. **70,523** filed Sept. **8, 1970,** now abandoned.

THE INVENTION

This invention relates to novel multiple gas discharge display/memory panels which have an electrical memory and which are capable of producing a visual display or representation of data such as numerals, letters, television display, radar displays, binary words, ets. More particularly, this invention relates to novel gas discharge display/memory panels having substantially decreased and more uniform operating voltages; that is, operating voltages which are essentially stable as a function of panel operating time. As used herein, voltage is defined as any voltage required for operation of the panel including firing and sustaining voltages as well as any other voltages for manipulation of the discharge.

Multiple gas discharge display and/or memory panels of the type with which the present invention is concerned are characterized by an ionizable gaseous medium, usually a mixture of at least two gases at an appropriate gas pressure, in a thin gas chamber or space between a pair of opposed dielectric charge storage members which are backed by conductor (electrode) members, the conductor members backing each dielectric member being transversely oriented to define a plurality of discrete discharge volumes and constituting a discharge unit. In some prior art panels the discharge units are additionally defined by surrounding or confining physical structure such as by cells or apertures in perforated glass plates and the like so as to be physically isolated relative to other units. In either case, with or without the confining physical structure, charges (electrons, ions) produced upon ionization of the gas of a selected discharge unit, when proper alternating operating potentials are applied to selected conductors thereof, are collected upon the surfaces of the dielectric at specifically defined locations and constitute an electrical field opposing the electrical field which created them so as to terminate the discharge for the remainder of the half cycle and aid in the initiation of a discharge on a succeeding opposite half cycle of applied voltage, such charges as are stored constituting an electrical memory.

Thus, the dielectric layers prevent the passage of any conductive current from the conductor members to the gaseous medium and also serve as collecting surfaces for ionized gaseous medium charges (electrons, ions) during the alternate half cycles of the A.C. operating potentials, such charges collecting first on one element or discrete dielectric surface area and then on an opposing elemental or discrete dielectric surface area on alternate half cycles to constitute an electrical memory.

An example of a panel structure containing non-physically isolated or open discharge units is disclosed in U.S. Pat. No. **3,499,167** issued to Theodore C. Baker, et al.

An example of a panel containing physically isolated units is disclosed in the article by D. L. Bitzer and H. G. Slottow entitled "The Plasma Display Panel — A Digitally Addressable Display With Inherent Memory," Proceeding of the Fall Joint Computer Conference, IEEE, San Francisco, Calif., November **1966,** pages **541–547.**

In the operation of the panel, a continuous volume of ionizable gas is confined between a pair of dielectric surface backed by conductor arrays forming matrix elements. The cross conductor arrays may be orthogonally related (but any other configuration of conductor arrays may be used) to define a plurality of opposed pairs of charge storage areas on the surfaces of the dielectric bounding or confining the gas. Thus, for a conductor matrix having H rows and C columns the number of elemental discharge volumes will be the product $H \times C$ and the number of elemental or discrete areas will be twice the number of elemental discharge volumes.

The gas is one which produces light (if visual display is an objective) and a copious supply of charges (ions and electrons) during discharge. In an open cell Baker, et al. type panel, the gas pressure and the electric field are sufficient to laterally confine charges generated on discharge within elemental or discrete volumes of gas between opposed pairs of elemental or discrete dielectric areas within the perimeter of such areas, especially in a panel containing non-isolated units.

As described in the Baker, et al. patent, the space between the dielectric surfaces occupied by the gas is such as to permit photons generated on discharge in a selected discrete or elemental volume of gas to pass freely through the gas space and strike surface areas of dielectric remote from the selected discrete volumes, such remote, photon struck dielectric surface areas thereby emitting electrons so as to condition other and more remote elemental volumes for discharges at a uniform applied potential.

With respect to the memory function of a given discharge panel, the allowable distance or spacing between the dielectric surfaces depends, inter alia, on the frequency of the alternating current supply, the distance typically being greater for lower frequencies.

While the prior art does disclose gaseous discharge devices having externally positioned electrodes for initiating a gaseous discharge, sometimes called "electrodeless discharges," such prior art devices utilize frequencies and spacings or discharge volumes and operating pressures such that although discharges are initiated in the gaseous medium, such discharges are ineffective or not utilized for charge generation and storage in the manner of the present invention.

The term "memory margin" is defined herein as

$$M.M. = \frac{V_f - V_s}{V_s}$$

where V_f is the magnitude of the applied voltage at which a discharge is initiated in a discrete conditioned (as explained in the aforementioned Baker, et al. patent) volume of gas defined by common areas of overlapping conductors and V_s is the magnitude of the minimum applied periodic alternating voltage sufficient to sustain discharges once initiated. It will be understood that basic electrical phenomena utilized in this invention is the generation of charges (ions and electrons) alternately storable at pairs of opposed or facing discrete points or areas on a pair of dielectric surfaces backed by conductors connected to a source of operating potential. Such stored charges result in an electrical

field opposing the field produced by the applied potential that created them and hence operate to terminate ionization in the elemental gas volume bewteen opposed or facing discrete points or areas of dielectric surface. The term "sustain a discharge" means producing a sequence of momentary discharges, one discharge for each half cycle of applied alternating sustaining voltage, once the elemental gas volume has been fired, to maintain alternate storing of charges at pairs of opposed discrete areas on the dielectric surfaces.

FIG. 1 is a partially cut-away plan view of the type of gaseous discharge display-memory panel which may incorporate the invention as connected to a diagrammatically illustrated source of operating potentials,

FIG. 2 is a cross-sectional view (enlarged, but not to proportional scale since the thickness of the gas volume, dielectric members and conductor arrays have been enlarged for purposes of illustration) taken on lines 2—2 of FIG. 1,

FIG. 3 is an explanatory partial cross-sectional view similar to FIG. 2 (enlarged, but not to proportional scale),

FIG. 4 is an isometric view of the type of a larger gaseous discharge display/memory panel which may incorporate the invention, and

FIG. 5 is a partial cross-sectional view similar to FIG. 3 showing the incorporation of the present invention.

FIGS. 1–4 and the following description of these drawings are from the previously mentioned Baker, et al. U.S. Pat. No. 3,499,167.

The invention utilizes a pair of dielectric films or coatings **10** and **11** separated by a thin layer or volume of a gaseous discharge medium **12**, said medium **12** producing a copious supply of charges (ions and electrons) which are alternately collectable on the surface of the dielectric members at opposed or facing elemental or discrete areas X and Y defined by the conductor matrix on non-gas-contacting sides of the dielectric members, each dielectric member presenting large open surface areas and a plurality of pairs of elemental X and Y areas. While the electrically operative structural members such as the dielectric members **10** and **11** and conductor matrixes **13** and **14** are all relatively thin (being exaggerated in thickness in the drawings) they are formed on and supported by rigid nonconductive support members **16** and **17** respectively.

Preferably, one or both of nonconductive support members **16** and **17** pass light produced by discharge in the elemental gas volumes. Preferably, they are transparent glass members and these members essentially define the overall thickness and strength of the panel. For example, the thickness of gas layer **12** as determined by spacer **15** is under 10 mils, and preferably about 5 to 6 mils, dielectric layers **10** and **11** (over the conductors at the elemental or discrete X and Y areas) is between 1 and 2 mils thick, and conductors **13** and **14** about 8,000 angstroms thick (tin oxide). However, support members **16** and **17** are much thicker (particularly larger panels) so as to provide as much ruggedness as may be desired to compensate for stresses in the panel. Support members **16** and **17** also serve as heat sinks for heat generated by discharges and thus minimize the effect of temperature on operation of the device. If it is desired that only the memory function be utilized, then none of the members need be transparent to light although for purposes described later herein it is preferred that one of the support members and members formed thereon be transparent to or pass ultraviolet radiation.

Except for being nonconductive or good insulators the electrical properties of support members **16** and **17** are not critical. The main function of support members **16** and **17** is to provide mechanical support and strength for the entire panel, particularly with respect to pressure differential acting on the panel and thermal shock. As noted earlier, they should have thermal expansion characteristics substantially matching the thermal expansion characteristics of dielectric layers **10** and **11.** Ordinary ¼ inch commercial grade soda lime plate glasses have been used for this purpose. Other glasses such as low expansion glasses or transparent devitrified glass can be used provided they can withstand processing and have expansion characteristics substantially matching expansion characteristics of the dielectric coatings **10** and **11.** For given pressure differentials and thickness of plates the stress and deflection of plates may be determined by following standard stress and strain formulas (see R. J. Roark, *Formulas for Stress and Strain*, McGraw-Hill, 1954).

Spacer **15** may be made of the same glass material as dielectric films **10** and **11** and may be an integral rib formed on one of the dielectric members and fused to the other members to form a bakeable hermetic seal enclosing and confining the ionizable gas volume **12.** However, a separate final hermetic seal may be effected by a high strength devitrified glass sealant **15S.** Tubulation **18** is provided for exhausting the space between dielectric members **10** and **11** and filling that space with the volume of ionizable gas. For large panels small bead-like solder glass spacers such as shown at **15B** may be located between conductor intersections and fused to dielectric members **10** and **11** to aid in withstanding stress on the panel and maintain uniformity of thickness of gas volume **12.**

Conductor arrays **13** and **14** may be formed on support members **16** and **17** by a number of well-known processes, such as photoetching, vacuum deposition, stencil screening, etc. In the panel shown in FIG. 4, the center-to-center spacing of conductors in the respective arrays is about 30 mls. Transparent or semitransparent conductive material such as tin oxide, gold or aluminum can be used to form the conductor arrays and should have a resistance less than 3,000 ohms per line. It is important to select a conductor material that is not attached during processing by the dielectric material.

It will be appreciated that conductor arrays **13** and **14** may be wires or filaments of copper, gold, silver or aluminum or any other conductive metal or material. For example, 1 mil wire filaments are commercially available and may be used in the invention. However, formed in situ conductor arrays are preferred since they may be more easily and uniformly placed on and adhered to the support plates **16** and **17.**

Dielectric layer members **10** and **11** are formed of an inorganic material and are preferably formed in situ as an adherent film or coating which is not chemically or physically effected during bake-out of the panel. One such material is a solder glass such as Kimble SG–68 manufactured by and commercially available from the assignee of the present invention.

This glass has thermal expansion characteristics substantially matching the thermal expansion characteristics of certain soda-lime glasses, and can be used as the

dielectric layer when the support members **16** and **17** are soda-lime glass plates. Dielectric layers **10** and **11** must be smooth and have a dielectric strength of about 1,000 v. and be electrically homogeneous on a microscopic scale (e.g., no cracks, bubbles, crystals, dirt, surface films, etc.). In addition, the surfaces of dielectric layers **10** and **11** should be good photoemitters of electrons in a baked out condition. However, a supply of free electrons for conditioning gas **12** for the ionization process may be provided by inclusion of a radioactive material within the glass or gas space. A preferred range of thickness of dielectric layers **10** and **11** overlying the conductor arrays **13** and **14** is between 1 and 2 mils. Of course, for an optical display at least one of dielectric layers **10** and **11** should pass light generated on discharge and be transparent or translucent and, preferably, both layers are optically transparent.

The preferred spacing between surfaces of the dielectric films is about 5 to 6 mils with conductor arrays **13** and **14** having center-to-center spacing of about 30 mils.

The ends of conductors **14-1 . . . 14-4** and support members **17** extend beyond the enclosed gas volume **12** and are exposed for the purpose of making electrical connection to interface and addressing circuitry **19.** Likewise, the ends of conductors **13-1 . . . 13-4** on support member **16** extend beyond the enclosed gas volume **12** and are exposed for the purpose of making electrical connection to interface and addressing circuitry **19.**

As in known display systems, the interface and addressing circuitry or system **19** may be relatively inexpensive line scan systems or the somewhat more expensive high speed random access systems. However, it is to be noted that a lower amplitude of operating potentials helps to reduce problems associated with the interface circuitry between the addressing system and the display/memory panel, per se. Thus, by providing a panel having greater uniformity in the discharge characteristics throughout the panel, tolerances and operating characteristics of the panel with which the interfacing circuitry cooperate, are made less rigid.

One mode of initiating operation of the panel will be described with reference to FIG. **3,** which illustrates the condition of one elemental gas volume **30** having an elemental cross-sectional area and volume which is quite small relative to the entire volume and cross-sectional area of gas **12.** The cross-sectional area of volume **30** is defined by the overlapping common elemental areas of the conductor arrays and the volume is equal to the product of the distance between the dielectric surfaces and the elemental area. It is apparent that if the conductor arrays are uniform and linear and are orthogonally (at right angles to each other) related each of elemental areas X and Y will be squares and if conductors of one conductor array are wider than conductors of the other conductor array, said areas will be rectangles. If the conductor arrays are at transverse angles relative to each other, other than 90°, the areas will be diamond shaped so that the cross-sectional shape of each volume is determined solely in the first instance by the shape of the common area of overlap between conductors in the conductor arrays **13** and **14.** The dotted lines **30'** are imaginary lines to show a boundary of one elemental volume about the center of which each elemental discharge takes place. As described earlier herein, it is known that the cross-sectional area of the discharge in a gas is affected by, inter alia, the pressure of the gas, such that, if desired, the discharge may even be constricted to within an area smaller than the area of conductor overlap. By utilization of this phenomena, the light production may be confined or resolved substantially to the area of the elemental cross-sectional area defined by conductor overlap. Moreover, by operating at such pressure charges (ions and electrons) produced on discharge are laterally confined so as to not materially affect operation of adjacent elemental discharge volumes.

In the instant shown in FIG. **3,** a conditioning discharge about the center of elemental volume **30** has been initiated by application to conductor **13-1** and conductor **14-1** firing potential V_x' as derived from a source **35** of variable phase, for example, and source **36** of sustaining potential V_s (which may be a sine wave, for example). The potential V_x' is added to the sustaining potential V_s as sustaining potential V_s increases in magnitude to initiate the conditioning discharge about the center of elemental volume **30** shown in FIG. **3.** There, the phase of the source **35** of potential V_x' has been adjusted into adding relation to the alternating voltage from the source **36** of sustaining voltage V_s to provide a voltage V_f', when switch **33** has been closed, to conductors **13-1** and **14-1** defining elementary gas volume **30** sufficient (in time and/or magnitude) to produce a light generating discharge centered about discrete elemental gas volume **30.** At the instant shown, since conductor **13-1** is positive, electrons **32** have collected on and are moving to an elemental area of dielectric member **10** substantially corresponding to the area of elemental gas volume **30** and the less mobile positive ions **31** are beginning to collect on the opposed elemental area of dielectric member **11** since it is negative. As these charges build up, they constitute a back voltage opposed to the voltage applied to conductors **13-1** and **14-1** and serve to terminate the discharge in elemental gas volume **30** for the remainder of a half cycle.

During the discharge about the center of elemental gas volume **30,** photons are produced which are free to move or pass through gas medium **12,** as indicated by arrows **37,** to strike or impact remote surface areas of photoemissive dielectric members **10** and **11,** causing such remote areas to release electrons **39.** Electrons **38** are, in effect, free electrons in gas medium **12** and condition each other discrete elemental gas volume for operation at a lower firing potential V_f which is lower in magnitude than the firing potential V_f' for the initial discharge about the center of elemental volume **30** and this voltage is substantially uniform for each other elemental gas volume.

Thus, elimination of physical obstructions or barriers between discrete elemental volumes, permits photons to travel via the space occupied by the gas medium **12** to impact remote surface areas of dielectric members **10** and **11** and provides a mechanism for supplying free electrons to all elemental gas volumes, thereby conditioning all discrete elemental gas volumes for subsequent discharges, respectively, at a uniform lower applied potential. While in FIG. **3** a single elemental volume **30** is shown, it will be appreciated that an entire row (or column) of elemental gas volumes may be maintained in a "fired" condition during normal operation of the device with the light produced thereby being masked or blocked off from the normal viewing area

and not used for display purposes. It can be expected that in some applications there will always be at least one elemental volume in a fired condition and producing light in a panel, and in such applications it is not necessary to provide separate discharge or generation of photons for purposes described earlier.

However, as described earlier, the entire gas volume can be conditioned for operation at uniform firing potentials by use of external or internal radiation so that there will be no need for a separate source of higher potential for initiating an initial discharge. Thus, by radiating the panel with ultraviolet radiation or by inclusion of a radioactive material within the glass materials or gas space, all discharge volumes can be operated at uniform potentials from addressing and interface circuit **19.**

Since each discharge is terminated upon a build up or storage of charges at opposed pairs of elemental areas, the light produced is likewise terminated. In fact, light production lasts for only a small fraction of a half cycle of applied alternating potential and depending on design parameters, is in the nanosecond range.

After the initial firing or discharge of discrete elemental gas volume **30** by a firing potential V_f', switch **33** may be opened so that only the sustaining voltage V_s from source **36** is applied to conductors **13-1** and **14-1.** Due to the storage of charges (e.g., the memory) at the opposed elemental areas X and Y, the elemental gas volume **30** will discharge again at or near the peak of negative half cycles of sustaining voltage V_s to again produce a momentary pulse of light. At this time, due to reversal of field direction, electrons **32** will collect on and be stored on elemental surface area Y of dielectric member **11** and positives ions **31** will collect and be stored on elemental surface area X of dielectric member **10.** After a few cycles of sustaining voltage V_s, the times of discharges become symmetrically located with respect to the wave form of sustaining voltage V_s. At remote elemental volumes, as, for example, the elemental volumes defined by conductor **14-1** with conductors **13-2** and **13-3,** a uniform magnitude or potential V_x from source **60** is selectively added by one or both switches **34-2** or **34-3** to the sustaining voltage V_s, shown as **36'**, to fire one or both of these elemental discharge volumes. Due to the presence of free electrons produced as a result of the discharge centered about elemental volume **30,** each of these remote discrete elemental volumes have been conditioned for operation at uniform firing potential V_f.

In order to turn "off" an elemental gas volume (i.e., terminate a sequence of discharge representing the "on" state), the sustaining voltage may be removed. However, since this would also turn off other elemental volumes along a row or column, it is preferred that the volumes be selectively turned off by application to selected on elemental volumes a voltage which can neutralize the charges stored at the pairs of opposed elemental areas.

This can be accomplished in a number of ways, as for example, varying the phase or time position of the potential from source **60** to where that voltage combined with the potential from source **36'** falls substantially below the sustaining voltage.

It is apparent that the plates **16-17** need not be flat but may be curved, curvature of facing surfaces of each plate being complementary to each other. While the preferred conductor arrangement is of the crossed grid type as shown herein, it is likewise apparent that where an infinite variety of two dimensional display patterns are not necessary, as where specific standardized visual shapes (e.g., numerals, letters, words, etc.) are to be formed and image resolution is not critical, the conductors may be shaped accordingly.

The devide shown in FIG. **4** is a panel having a large number of elemental volumes similar to elemental volume **30** (FIG. **3**). In this case more room is provided to make electrical connection to the conductor arrays **13'** and **14'**, respectively, by extending the surfaces of support members **16'** and **17'** beyond seal **15S'**, alternate conductors being extended on alternate sides. Conductor arrays **13'** and **14'** as well as support members **16'** and **17'** are transparent. The dielectric coatings are not shown in FIG. **4** but are likewise transparent so that the panel may be viewed from either side.

In accordance with this invention, it has been surprisingly discovered that the magnitude of the gaseous discharge panel operating voltage is substantially decreased and the uniformity or stability of such voltage as a function of gaseous discharge panel operating time is significantly enhanced and improved by applying a first layer of an oxide selected from aluminum, titanium, zirconium, hafnium, and silicon and a second layer of lead oxide to the charge storage surface of the dielectric material. More particularly, a first layer of at least one oxide of Al, Ti, Zr, Hf, and Si and a second layer of lead oxide over the first oxide layer are applied to the dielectric material charge storage surface so as to provide gaseous discharge panel operating voltages which are substantially decreased and which do not significantly vary or change over a given period of panel operating time, thereby substantially increasing the effective and useful operating life of the gaseous discharge panel.

In one embodiment hereof, at least one of the oxide layers is applied directly to the surface of the dielectric material.

In another embodiment hereof, at least one of the oxide layers is formed in situ on the dielectric surface, e.g., by applying the elemental metal or metalloid (or a source thereof) to the dielectric surface followed by oxidation. One such in situ process comprises applying metal or metalloid melt to the dielectric followed by oxidation of the melt during the cooling thereof so as to form the oxide layer. Another in situ process comprises applying an oxidizable source of the elemental metal or metalloid to the surface. Typical of such oxidizable sources include minerals and/or compounds containing the metal or metalloid, especially those organometals or organometalloids which are readily heat decomposed or pyrolyzed.

Each oxide layer (or a source thereof) is applied to the dielectric surface by any convenient means including not by way of limitation vapor deposition; vacuum deposition; chemical vapor deposition; wet spraying upon the surface a mixture or solution of the oxide suspended or dissolved in a liquid followed by evaporation of the liquid; dry spraying of the oxide upon the surface; electron beam evaporation; plasma flame and/or arc spraying and/or deposition; and sputtering target techniques.

Each selected oxide is applied to (or formed in situ on) the dielectric surface as a very thin film or layer, the thickness and amount of both oxide films or layers being sufficient to substantially decrease and signifi-

cantly stabilize the panel operating voltages as a function of panel operating time. In one highly preferred embodiment hereof, the two oxide layers are applied to a total thickness and quantity sufficient to synergistically decrease the panel operating voltages; that is, to provide a panel operating voltage on both layers which is less than the operating voltage for either layer alone. In the usual practice hereof, each of the two oxide layers is applied to or formed on the dielectric material surface to a thickness of at least about 200 angstrom units per layer with a range of about 200 angstrom units per layer up to about 1 micron (10,000 angstrom units) per layer. As shown in FIG. **5**, first oxide layers **118** and **119** are disposed contiguously to the surface of dielectric layers **10** and **11**, respectively. Second oxide layers **120** and **121** are disposed contiguously on the first oxide layers **118** and **119**, respectively.

As used herein, the terms "film or layer" are intended to be all inclusive of other similar terms such as deposit, coating, finish, spread, covering, etc.

In the fabrication of a gaseous discharge panel, the dielectric material is typically applied to and cured on the surface of a supporting glass substrate or base to which the electrode or conductor elements have been previously applied. The glass substrate may be of any suitable composition such as a soda lime glass composition. Two glass substrates containing electrodes and cured dielectric are then appropriately heat sealed together so as to form a panel. In the preferred practice of this invention, each oxide layer is applied to the surface of the cured dielectric before the panel heat sealing cycle.

Depending upon the specific oxide layers and combinations thereof utilized, the practice of this invention has been found to be especially beneficial over given periods of panel operating time. Best results are typically realized after appropriate aging of the panel, the required amount of aging being a function of the oxides used. Panel aging is defined as the accumulated total operating time for the panel.

The following examples are intended to illustrate some of the best embodiments contemplated by the inventors in the practice of this invention.

EXAMPLE I

A layer of aluminum oxide (Al_2O_3) was deposited to a relatively uniform thickness of about 1000 angstrom units on the respective exposed surfaces of two cured dielectric material layers, each dielectric layer having been previously applied and cured onto (electrodes containing) glass substrates.

The aluminum oxide was deposited by means of an electron beam evaporation technique. The dielectric composition was a lead borosilicate consisting of 73.3% by weight PbO, 13,4% by weight B_2O_3, and 13.3% by weight SiO_2. The glass substrates were of a soda lime composition containing about 73% by weight SiO_2, about 13% by weight Na_2O, about 10% by weight CaO, about 3% by weight MgO, about 1% by weight Al_2O_3, and small amounts (less than 1%) of Fe_2O_3, K_2O, As_2O_3. The electrode lines or conductor arrays were of hanovia gold.

The two substrates were heat sealed together (using a standard solder glass) so as to form a gaseous discharge panel of the open cell Baker, et al. kind. After an appropriate vacuum process, the panel was filled with an inert ionizable gas consisting of 99.9% atoms of neon and 0.1% atoms of argon. After aging of the panel for about 50 hours during which time the dynamic sustaining voltage increased by about +18 volts, the voltage leveled off with a change of only −2 volts over the next 500 hours of panel operating time. The magnitude of the dynamic sustaining voltage after aging was about 225 volts.

EXAMPLE II

The panel fabrication of Example I was repeated using a layer of lead oxide (1,000 angstrom units thickness) instead of aluminum oxide. After aging of the panel for about 3 hours during which time the dynamic sustaining voltage increased by about −10 volts, the voltage leveled off with a change of only +4 volts over the next 570 hours of panel operating time. The magnitude of the dynamic sustaining voltage after aging was about 145 volts.

EXAMPLE III

The panel fabrication of Examples I and II was repeated using a first layer of aluminum oxide (1,000 angstrom units thickness) and a second layer (over the first layer) of lead oxide (1,000 angstrom units thickness). After aging of the panel for about 30 hours during which time the dynamic sustaining voltage decreased by about −4, the voltage leveled off with substantially no change over the next 530 hours of panel operating time. The magnitude of the dynamic sustaining voltage after aging was about 115 volts.

EXAMPLE IV

The panel fabrication of Examples I, II, and III was repeated using no oxide layers on the dielectric. The panel required about 100 hours of aging before the dynamic sustaining voltage leveled off at a magnitude of about 140 volts.

The foregoing examples illustrate that when a layer of oxide is applied to the dielectric surface as in Examples I and II, the aging time for the resulting fabricated gaseous discharge panel is substantially decreased; e.g., in comparison with Example IV wherein no oxide layer was used.

When at least two oxide layers are applied to the dielectric in accordance with this invention, as in Example III, the aging time is also substantially decreased; e.g., in comparison with Example IV. However, in addition, the magnitude of the dynamic sustaining voltage is also substantially decreased in comparison with all of the other examples, synergistically with respect to Examples I and II.

I claim:

1. In the method of manufacturing a gaseous discharge panel characterized by an ionizable gaseous medium in a gas chamber formed by a pair of opposed dielectric material charge storage members which are respectively backed by a series of parallel-like electrode members, the electrode members being transversely oriented with respect to the electrode members behind the opposing dielectric material storage members so as to define a plurality of discrete discharge volumes constituting a discharge unit, and wherein the gas is selectively ionized within each discharge unit by operating voltages applied to the transversely oriented electrode members, the improvement comprising:

a. depositing on the charge storage surface of each dielectric member a first layer of at least one oxide

selected from the group consisting of aluminum oxide, titanium oxide, zirconium oxide, hafnium oxide and silicon oxide, said deposited layer having a thickness of at least about 200 angstrom units;

b. and depositing a second layer consisting of lead oxide, said second layer having a thickness of at least about 200 angstrom units.

2. In the method as defined in claim 1 wherein each layer is disposed at a thickness in the range of from about 200 angstron units up to about 10,000 angstrom units.

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